Atto Docket No.: 436589 Express Mail Label No.: EV413219918US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Applicant(s)	Marcus-Christian Amann	Examiner	Not Yet Assigned			
Serial No.	10/535,688	Group Art No.	Not Yet Assigned			
Filed	May 19, 2005	Confirmation No.	4283			
For	Surface-Emitting Semi-Conductor Lasers Having Buried Tunnel Junctions and Methods of Producing Same					
	Same		December 28, 2005			
Commissione P.O. Box 145 Alexandria, V						
	INFORMATION DISCLOSURE STAT	EMENT TRANSM	ITTAL			
Dear Sir:						
This Informa	tion Disclosure Statement is submitted:					
	under 37 CFR 1.97(b), or (Within three months of filing national application, or dat first office action on the merits, whichever occurs last)	e of entry of national applicat	ion, or before mailing date of			
under 37 CFR 1.97(c) together with either a: Statement under 37 CFR 1.97(e), or a \$180 fee under 37 CFR 1.17(p), or (After the CFR 1.97(b) time period, but before final action or notice of allowance, which ever occurs first						
	under 37 CFR 1.97(d) together with a: Statement under 37 CFR 1.97(e)(1) or (2), and a \$180.00 fee set forth in 37 CFR 1.17(p). (Filed after final action, a notice of allowance, on or before payment of issue fee)					
pendency of	se charge to Deposit Account 12-0600 the this application, please charge any fees ount 12-0600 pursuant to 37 CFR 1.25.	e sum of \$0.00. At a required or credit an	any time during the y overpayment to			
		TO 1440 T.C	: Disalaguma			

Applicant(s) submit herewith Form PTO 1449 – Information Disclosure Statement together with copies of non-U.S. patents, publications or other information (if any) of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of the application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.

A concise explanation of the relevance of foreign language patents, foreign language publications and other foreign language information listed on PTO Form 1449, as presently understood by the individual(s) designated in 37 CFR 1.56(c) most knowledgeable about the content is given on the attached sheet, or where a foreign language patent is cited in

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a search report or other action by a foreign patent office in a counter part foreign application, an English language version of the search report or action which indicates the degree of relevance found by the foreign office is listed on form PTO 1449 and is enclosed herewith.

It is requested that the information disclosed herein be made of record in this application.

Respectfully submitted,

LATHROP & GAGE LC

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PTO/SB/08a (08-03)

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Substitute for form 1449A/PTO				Complete if Known		
0000				Application Number	10/468,183	
INFO	RMATION	DIS	CLOSURE	Filing Date	April 28, 2004	
STATEMENT BY APPLICANT				First Named Inventor	Markus-Christian Amann	
SIAI	CIVICIAI D			Art Unit	2828	
	(Use as many she	ets as	necessary)	Examiner Name	Minsun Oh Harvey	
Sheet	1	of	2	Attorney Docket Number	411883	

	U.S. PATENT DOCUMENTS					
Examiner Cite Initials * No.1		Document Number	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant	
Initials *	No.1	Number - Kind Code ² (if known)	MM-DD-YYYY		Figures Appear	
		US-5,661,075	08-26-1997	Grodzinski, et al.		
		US- 6,052,398	04-18-2000	Brillouet, et al.		
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	FOREIGN PATENT DOCUMENTS						
		Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
Examiner Cite Initials* No.1	Country Code ³ - Number ⁴ - Kind Code ⁵ (<i>if known</i>)	T ⁶					
		DE 101 07 349 A1	08-29-2002	Amann, Markus-Christian			
	-	WO 98/07218 A	02-19-1998	Gore & Associates, Inc.			
		EP 0 184 117 A	06-11-1986	Siemens Ag			
	-						

Examiner	Date
Signature	Considered

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional). See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. Applicant is to place a check mark here if English language Translation is attached.

Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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Substitute for form 1449B/PTO Complete if Known Application Number 10/468,183 INFORMATION DISCLOSURE Filing Date April 28, 2004 STATEMENT BY APPLICANT First Named Inventor Markus-Christian Amann Art Unit (Use as many sheets as necessary) Examiner Name Minsun Oh Harvey Sheet of Attorney Docket Number 411883

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Τ²
		ORTSIEFER, M, et al.: "Low-Threshold Index-Guided 1.5 Murn Long-Wavelenght Vertical-Cavity Surface- Emitting Laser With High Efficiency", Applied Physics Letters, American Institute of Physics, New York, US, pg. 2179-2181, April 17, 2000	
		NAKAGAWA, S., et al.: "88° Continuous-Wave Operation Of Apertured, Intracavity Contacted, 1.55 Mum Vertical-Cavity Surface-Emitting Lasers" Applied Physics Letters, American Institute of Physics, New York, US, pg 1337-1339, March 5, 2001	
-		ORTSIEFER, M., et al: "Submilliamp Long-Wavelength InP-Based Vertical-Cavity Surface-Emitting Laser With Stable Linear Polarisation" Electronics Letters, IEE Stevenage, pg. 1124-1126, June 22, 2000	
		ORTSIEFER, M, et al: "90°C Continuous-Wave Operation Of 1.83-Mum Vertical-Cavity Surface-Emitting Lasers" IEEE Photonics Technology Letters, IEE Inc., New York, US, pgs 1435-1437, November 2000	
		SCHRAUD, G, et al: "Substrateless Singlemode Vertical Cavity Surface-Emitting GaAs/GaALAs Laser Diode" Electronics Letters, IEE Stevenage, GB, pgs 238-239, February 3, 1994	
		LIAU, Z.L., et al: "A Novel Technique For Gainasp/Inp Buried Heterostructure Laser Fabrication" Applied Physics Letters, American Institute of Physics, New York, US, pg 568-570, April 1, 1982	
		International Preliminary Examination Report for PCT/EP2003/012433	

Examiner	Date	
Signature	 Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance

^{*}EXAMINEH: Initial if reference considered, whether or not citation is in conformance will here to use the initial if reference considered, whether or not citation is in conformance will here to use the initial in reference considered, whether or not citation is in conformance will here to use the initial ini to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.